Transistor PNP Silicon

COLLECTOR 3 BASE 1 EMITTER

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	VCEO	-40	Vdc
Collector-Emitter Voltage	VCES	-40	Vdc
Collector-Base Voltage	VCBO	-40	Vdc
Emitter-Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current — Continuous	IC	_	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	1.5 12	mW mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

MPS4250



THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage (I _C = -5.0 mA)	V(BR)CES	-40	_	Vdc	
Collector-Emitter Sustaining Voltage ⁽¹⁾ (I _C = -5.0)	V(BR)CEO(sus)	-40	_	Vdc	
Collector–Base Breakdown Voltage (IC = –10 μA)	V(BR)CBO	-40	_	Vdc	
Emitter-Base Breakdown Voltage (I _E = -10 μA)	V(BR)EBO	-5.0	_	Vdc	
Collector Cutoff Current ($V_{CB} = -50 \text{ V}$) ($V_{CB} = -40 \text{ V}$, $T_{A} = 65^{\circ}\text{C}$)	ICBO	_ _ _	-10 -3.0	nA μA	
Emitter Cutoff Current (V _{EB} = -3.0 V)	I _{EBO}	_	-20	nA	

^{1.} Pulse Test: Pulse Width = $300 \mu s$; Duty Cycle = 2.0%.



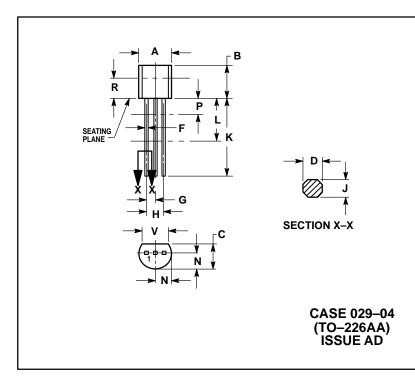
MPS4250

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS			•	
DC Current Gain $(I_C = -1.0 \text{ mA}, V_{CE} = -5.0 \text{ V})$ $(I_C = -10 \text{ mA}, V_{CE} = -5.0 \text{ V})$	hFE	250 250	_	_
Collector – Emitter Saturation Voltage ⁽¹⁾ (I _C = -10 mA, I _B = -0.5 mA)	VCE(sat)	_	-0.25	Vdc
Base-Emitter Saturation Voltage ⁽¹⁾ $(I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA})$	V _{BE} (sat)	_	-0.9	Vdc
SMALL-SIGNAL CHARACTERISTICS	•		•	
Output Capacitance (V _{CB} = -5.0 V, f = 1.0 MHz)	C _{obo}	_	6.0	pF
Input Capacitance $(V_{EB} = -0.5 \text{ V}, f = 1.0 \text{ MHz})$	C _{ibo}	_	16	pF
Small–Signal Current Gain ($I_C = -1.0$ mA, $V_{CE} = -5.0$ V, $f = 1.0$ kHz) ($I_C = -0.5$ mA, $V_{CE} = -5.0$ V, $f = 20$ MHz)	h _{fe}	250 2.0	800 —	_
Noise Figure $ (I_{C} = -20 \ \mu\text{A}, \ V_{CE} = -5.0 \ \text{V}, \ R_{S} = 10 \ \text{k}\Omega, \ f = 1.0 \ \text{kHz}, \ P_{BW} = 150 \ \text{Hz}) $ $ (I_{C} = -250 \ \mu\text{A}, \ V_{CE} = -5.0 \ \text{V}, \ R_{S} = 1.0 \ \text{k}\Omega, \ f = 1.0 \ \text{kHz}, \ P_{BW} = 150 \ \text{Hz}) $	NF	_ _	2.0 2.0	dB

^{1.} Pulse Test: Pulse Width = $300 \mu s$; Duty Cycle = 2.0%.

PACKAGE DIMENSIONS



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
ν	0.135		3 43	

STYLE 1: PIN 1. EMITTER

2. BASE 3. COLLECTOR

MPS4250

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